



#16/D
7/17/03
Am Th

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Douglas D. Coolbaugh, et al.

Examiner: Cuong Q. Nguyen

Serial No: 09/516,615

Art Unit: 2811

Filed: March 1, 2000

Docket: BUR919990190US1 (13020)

For: METHOD OF FABRICATING A
POLYSILICON CAPACITOR UTILIZING
FET AND BIPOLAR BASE POLYSILICON
LAYERS

Dated: July 7, 2003

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RECEIVED
JUL 16 2003
1600
TECHNOLOGY CENTER

RESPONSE

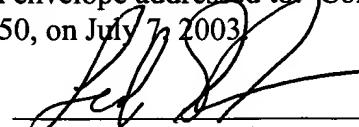
Sir:

In response to the Office Action dated March 7, 2003, applicants submit the following amendments and remarks for entry of record in the above-identified patent application.

CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexander, VA 22313-1450, on July 7, 2003.

Dated: July 7, 2003


Leslie S. Szivos